# **General Purpose Transistors**

# **NPN Silicon**

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-416/SC-75 package which is designed for low power surface mount applications.

#### **Features**

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant\*

## **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	$V_{CEO}$	40	Vdc
Collector – Base Voltage	V <sub>CBO</sub>	60	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous	Ic	200	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) @T <sub>A</sub> = 25°C Derated above 25°C	P <sub>D</sub>	200 1.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) @T <sub>A</sub> = 25°C Derated above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction–to–Ambient (Note 2)	$R_{\theta JA}$	400	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 × 1.0 Inch Pad



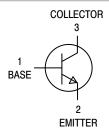
ON Semiconductor®

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# GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT



SOT-416/SC-75 CASE 463 STYLE 1



## **MARKING DIAGRAM**



AM = Device Code

M = Date Code\*

- Ph Free Packs

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBT3904TT1G	SOT-416 (Pb-Free)	3,000 Tape & Reel
SMMBT3904TT1G	SOT-416 (Pb-Free)	3,000 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

<sup>\*</sup>Date Code orientation may vary depending upon manufacturing location.

# ${\bf MMBT3904TT1G,\,SMMBT3904TT1G}$

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C unless otherwise noted)

	Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					1	
Collector – Emitter Breakdo (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)</sub> CEO	40	-	Vdc		
Collector – Base Breakdown Voltage ( $I_C = 10 \mu Adc, I_E = 0$ )			60	-	Vdc	
Emitter – Base Breakdown (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	Voltage	V <sub>(BR)EBO</sub>	6.0	-	Vdc	
Base Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)			-	50	nAdc	
Collector Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)			– 50 nAd		nAdc	
ON CHARACTERISTICS	Note 3)	1		1	1	
DC Current Gain ( $I_C = 0.1 \text{ mAdc}, V_{CE} = 1$ ) ( $I_C = 1.0 \text{ mAdc}, V_{CE} = 1$ ) ( $I_C = 10 \text{ mAdc}, V_{CE} = 1$ ) ( $I_C = 50 \text{ mAdc}, V_{CE} = 1$ ) ( $I_C = 100 \text{ mAdc}, V_{CE} = 1$ )	.0 Vdc) 0 Vdc) 0 Vdc)	h <sub>FE</sub>	40 70 100 60 30	- 300 - -	_	
	V <sub>CE(sat)</sub>	<u>-</u> -	0.2 0.3	Vdc		
Base – Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mAdc}$ ) ( $I_C = 50 \text{ mAdc}$ , $I_B = 5.0 \text{ mAdc}$ )			0.65	0.85 0.95	Vdc	
SMALL-SIGNAL CHARA	CTERISTICS	-		1	1	
Current – Gain – Bandwidtl (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 20	f <sub>T</sub>	300	_	MHz		
Output Capacitance (V <sub>CB</sub> = 5.0 Vdc, I <sub>E</sub> = 0, f	C <sub>obo</sub>	-	4.0	pF		
Input Capacitance (V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f	C <sub>ibo</sub>	-	8.0	pF		
Input Impedance (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0	h <sub>ie</sub>	1.0	10	kΩ		
Voltage Feedback Ratio (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0	h <sub>re</sub>	0.5	8.0	X 10 <sup>-4</sup>		
Small – Signal Current Gain (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz)			100	400	_	
Output Admittance (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz)			1.0	40	μmhos	
Noise Figure ( $V_{CE}$ = 5.0 Vdc, $I_{C}$ = 100 $\mu$ Adc, $R_{S}$ = 1.0 k $\Omega$ , f = 1.0 kHz)			-	5.0	dB	
SWITCHING CHARACTE	RISTICS					
Delay Time (V <sub>CC</sub> : MM	= 3.0 Vdc, V <sub>BE</sub> = -0.5 Vdc) BT3904TT1G, SMMBT3904TT1G	t <sub>d</sub>		35		
	0 mAdc, I <sub>B1</sub> = 1.0 mAdc) BT3904TT1G, SMMBT3904TT1G	t <sub>r</sub>	_	35	- ns	
	= 3.0 Vdc, I <sub>C</sub> = 10 mAdc) BT3904TT1G, SMMBT3904TT1G	t <sub>s</sub>		200		
Fall Time (I <sub>B1</sub> = MM	I <sub>B2</sub> = 1.0 mAdc) BT3904TT1G, SMMBT3904TT1G	t <sub>f</sub>	_	50		

<sup>3.</sup> Pulse Test: Pulse Width  $\leq 300 \,\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

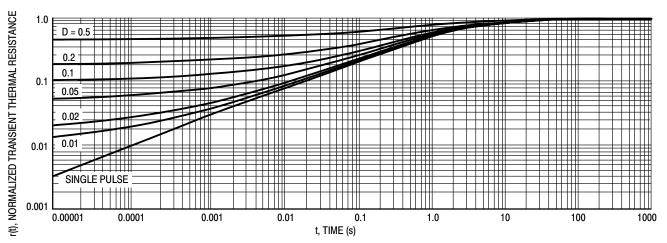
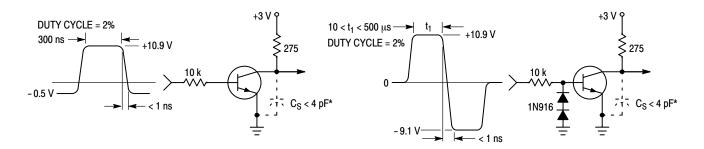


Figure 1. Normalized Thermal Response



\* Total shunt capacitance of test jig and connectors

Figure 2. Delay and Rise Time Equivalent Test Circuit

Figure 3. Storage and Fall Time Equivalent Test Circuit

### TYPICAL TRANSIENT CHARACTERISTICS

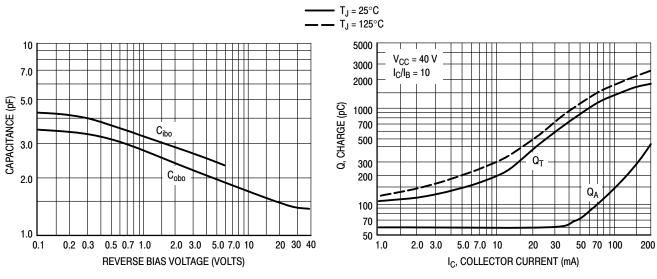
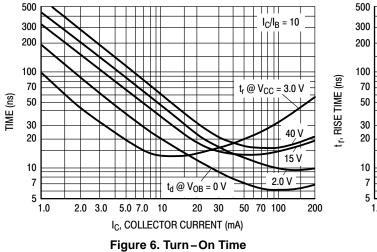


Figure 4. Capacitance

Figure 5. Charge Data



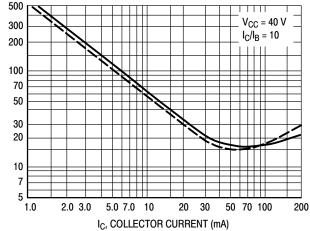
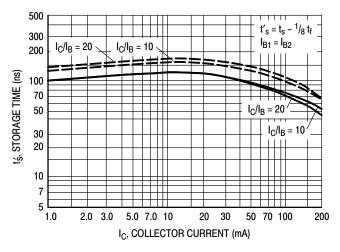


Figure 7. Rise Time



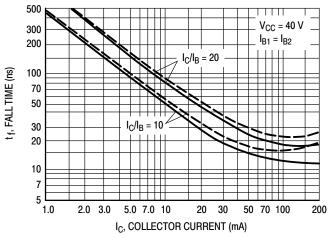
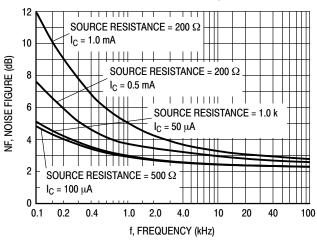


Figure 8. Storage Time

Figure 9. Fall Time

# TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$ 



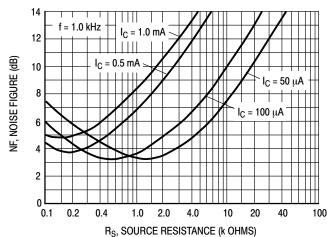
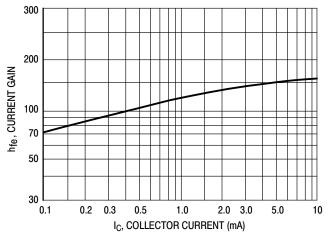


Figure 10. Noise Figure

Figure 11. Noise Figure

## h PARAMETERS

 $(V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$ 



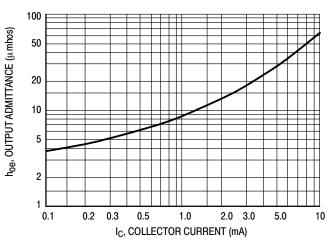
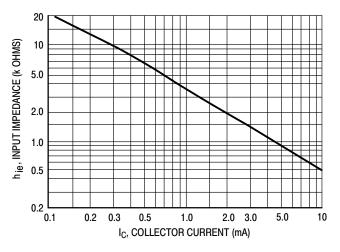


Figure 12. Current Gain

Figure 13. Output Admittance



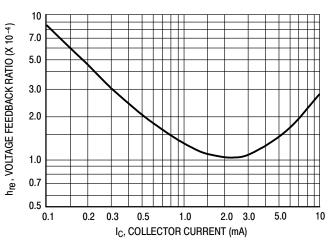


Figure 14. Input Impedance

Figure 15. Voltage Feedback Ratio

## TYPICAL STATIC CHARACTERISTICS

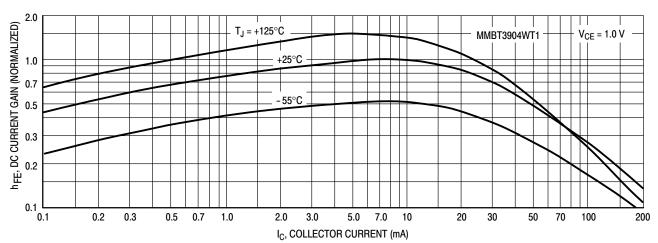


Figure 16. DC Current Gain

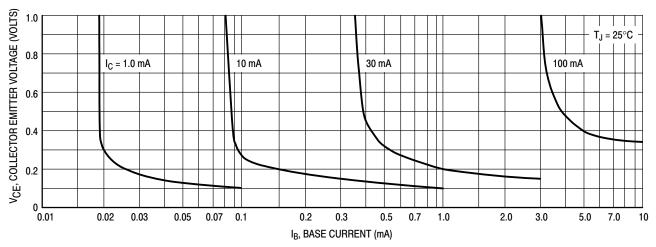


Figure 17. Collector Saturation Region

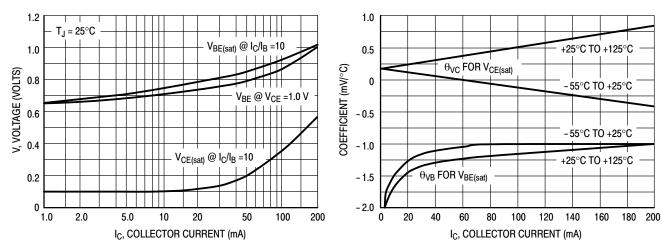


Figure 18. "ON" Voltages

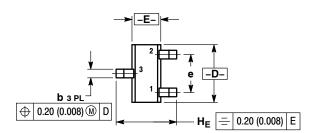
**Figure 19. Temperature Coefficients** 

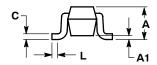




SC-75/SOT-416 **CASE 463** ISSUE G

**DATE 07 AUG 2015** 





STYLE 1: PIN 1. BASE 2. EMITTER STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE 3. COLLECTOR 3. CATHODE STYLE 4: STYLE 5: PIN 1. CATHODE 2. CATHODE PIN 1. GATE 2. SOURCE

3. DRAIN

## **GENERIC MARKING DIAGRAM\***

3. ANODE



XX = Specific Device Code Μ = Date Code

= Pb-Free Package

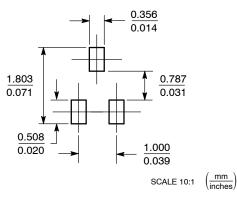
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

#### NOTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14,5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.061	0.063	0.065
E	0.70	0.80	0.90	0.027	0.031	0.035
е	1.00 BSC			C	0.04 BSC	
L	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.060	0.063	0.067

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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